NSN 5961-01-014-4993

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-014-4993 **Inclosure Material:** Metal **Overall Length:** 3.000 inches **Overall Height:** 1.000 inches **Overall Width:** 3.000 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Bracket and unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 300.0 reverse voltage, peak **Current Rating Per Characteristic:** 650.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 190.0 degrees celsius junction **Terminal Type And Quantity:** 1 flange and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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